

## DESCRIPTION

LCXXCI a 3.3V-30V bi-directional TVS diode , utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making his device an ideal solution for protecting voltage sensitive high-speed data lines. The LCX XCI has a low capacitance with a typical value at 1pF, and complies with the IEC61000-4-2(ESD) standard with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into a lead free SOD-323 package. The small size, low capacitance and high ESD surge protection make LCXXCI an idea choice to protect cell phone, wireless systems, and communication equipment.

## APPLICATIONS

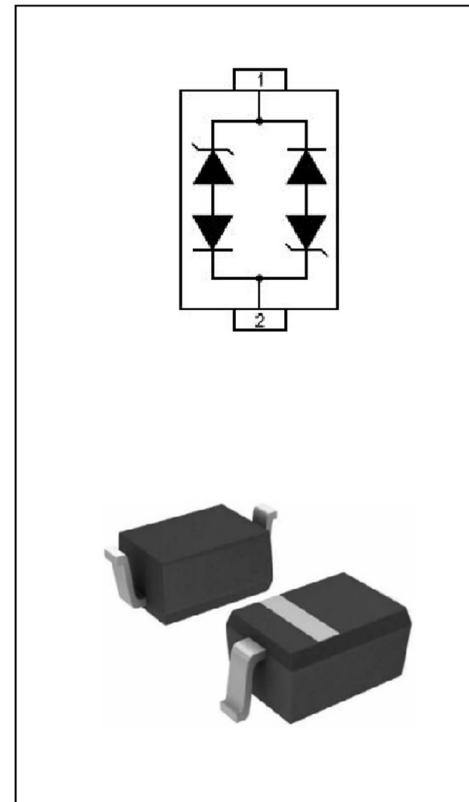
- ◊ USB Ports.
- ◊ Smart Phones.
- ◊ Wireless Systems.
- ◊ Ethernet 10/100/1000 Base T.

## FEATURES

- ◊ 350W peak pulse power (8/20 $\mu\text{s}$ ).
- ◊ Ultra low capacitance: 1.2pF typical.
- ◊ Ultra low leakage: nA level.
- ◊ Low operating :3.3V ,5V,8V,12V,15V,18V,24V,30V.
- ◊ Low clamping voltage.
- ◊ Protects one power line or data line.
- ◊ Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test Air discharge:  $\pm 30\text{kV}$  Contact discharge:  $\pm 30\text{kV}$ .
  - IEC61000-4-4 (EFT) 40A (5/50ns).
- ◊ RoHS Compliant.
- ◊ Package: SOD-323.

## ORDERING INFORMATION

Part NO	packaging	Reel Size
LC03CI	3000/Tape & Reel	7 inch
LC05CI	3000/Tape & Reel	7 inch
LC08CI	3000/Tape & Reel	7 inch
LC12CI	3000/Tape & Reel	7 inch
LC15CI	3000/Tape & Reel	7 inch
LC18CI	3000/Tape & Reel	7 inch
LC24CI	3000/Tape & Reel	7 inch
LC30CI	3000/Tape & Reel	7 inch



## DEVICE CHARACTERISTICS

### Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	P <sub>pp</sub>	350	W
Peak Pulse Current (8/20μs)	I <sub>pp</sub>	22-6	A
ESD per IEC 61000-4-2 (Air)	V <sub>ESD</sub>	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	T <sub>J</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

### ELECTRICAL CHARACTERISTICS( $T_A=25^\circ\text{C}$ unless otherwise specified)

#### LC03CI

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>				3.3	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1mA	4		6	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 3.3 V			0.2	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1A (8 x 20μs pulse)			5	V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 22A (8 x 20μs pulse)			16	V
Junction Capacitance	C <sub>J</sub>	VR = 0V, f = 1MHz		1.2		pF

#### LC05CI

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>				5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>T</sub> = 1mA	6.2	6.8	8.0	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5.0 V			0.5	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 1A (8 x 20μs pulse)		8.5		V
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> = 22A (8 x 20μs pulse)		17.0	20	V
Junction Capacitance	C <sub>J</sub>	VR = 0V, f = 1MHz		1.0	1.5	pF

<b>LC08CI</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				8.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	8.5			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 8 \text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			13	V
Clamping Voltage	$V_C$	$I_{PP} = 18\text{A} (8 \times 20\mu\text{s pulse})$			19.5	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1		pF

<b>LC12CI</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				12.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	13.3			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 12 \text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			18	V
Clamping Voltage	$V_C$	$I_{PP} = 12\text{A} (8 \times 20\mu\text{s pulse})$			29	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1.2		pF

<b>LC15CI</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				15.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	16.7			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 15 \text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			22	V
Clamping Voltage	$V_C$	$I_{PP} = 10\text{A} (8 \times 20\mu\text{s pulse})$			32	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1.2		pF

### **LC18CI**

<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				18.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	20			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 18\text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			26	V
Clamping Voltage	$V_C$	$I_{PP} = 10\text{A} (8 \times 20\mu\text{s pulse})$			35	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1		pF

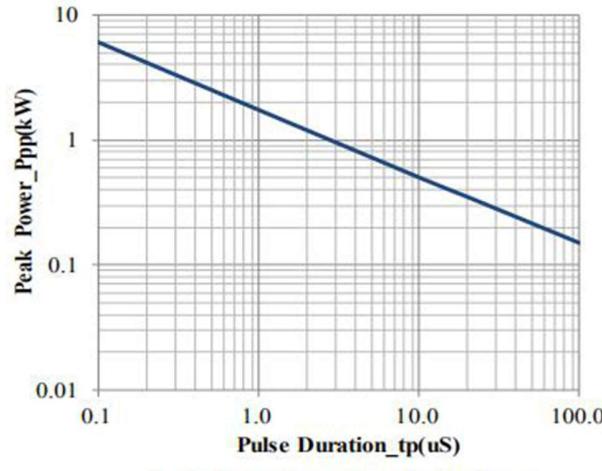
### **LC24CI**

<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				24.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	26.7			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 24\text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			43	V
Clamping Voltage	$V_C$	$I_{PP} = 8\text{A} (8 \times 20\mu\text{s pulse})$			55	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1.2		pF

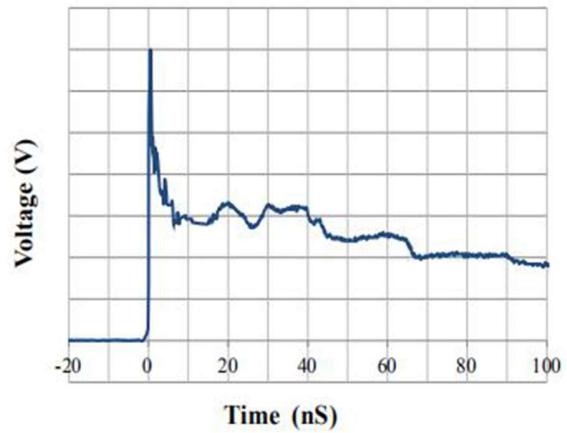
### **LC30CI**

<b>Parameter</b>	<b>Symbol</b>	<b>Test Condition</b>	<b>Min</b>	<b>Typ</b>	<b>Max</b>	<b>Unit</b>
Reverse Working Voltage	$V_{RWM}$				30.0	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	33.3			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 30\text{ V}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A} (8 \times 20\mu\text{s pulse})$			50	V
Clamping Voltage	$V_C$	$I_{PP} = 10\text{A} (8 \times 20\mu\text{s pulse})$			75	V
Junction Capacitance	$C_J$	$VR = 0\text{V}, f = 1\text{MHz}$		1.2		pF

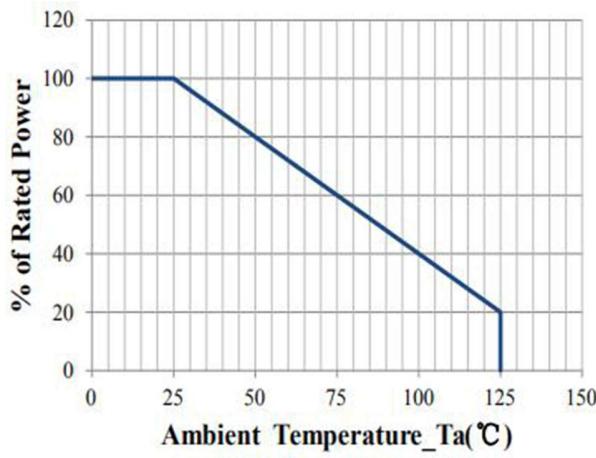
**TYPICAL CHARACTERISTICS**( $T_A=25^\circ\text{C}$  unless otherwise Specified)



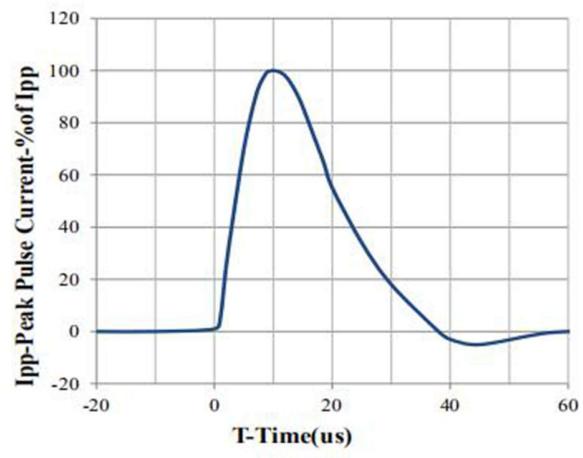
Peak Pulse Power vs. Pulse Time



IEC61000-4-2 Pulse Waveform

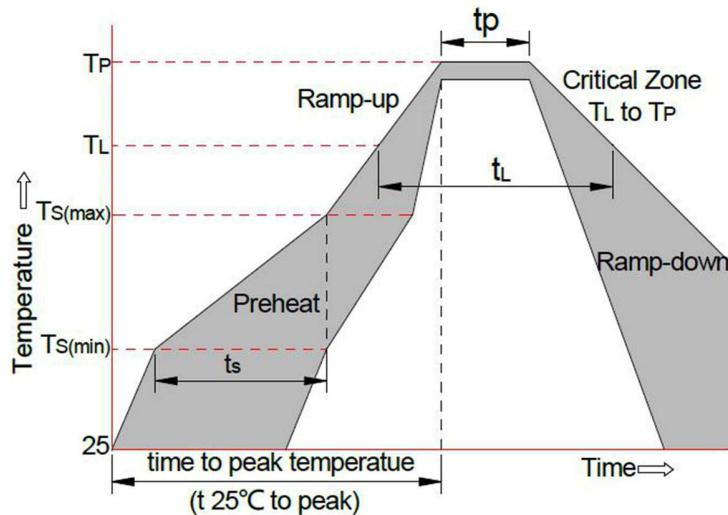


Power Derating Curve



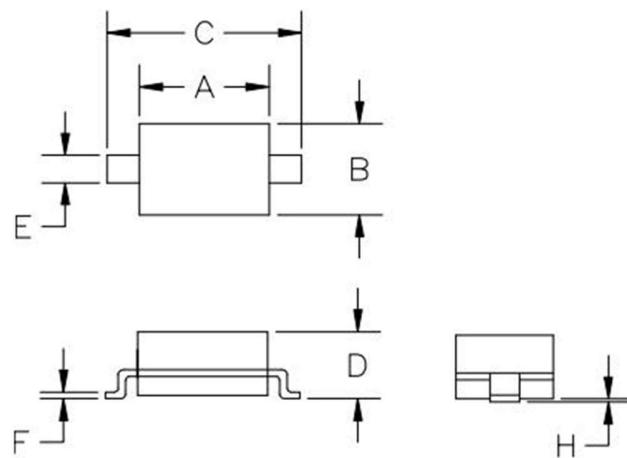
8 X 20us Pulse Waveform

## SOLDERING PARAMETERS



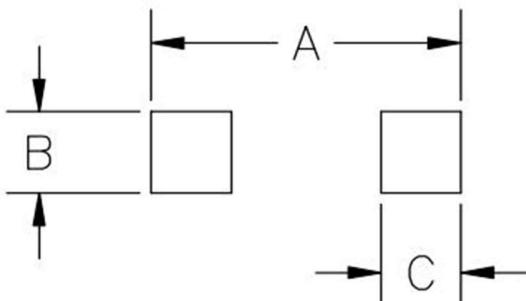
Reflow Condition		Pb-Free Assembly
Pre-heat	-Temperature Min (Ts <sub>(min)</sub> )	+150°C
	-Temperature Max (Ts <sub>(max)</sub> )	+200°C
	-Time (Min to Max) (ts)	60-180 secs
Average ramp up rate( Liquid us Temp (T <sub>L</sub> ) to peak)		3°C/sec. Max
T <sub>S (max)</sub> to T <sub>L</sub> -Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature (T <sub>L</sub> ) (Liquid us)	+217°C
	-Temperature (t <sub>L</sub> )	60-150 secs
Peak Temp (Tp)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (tp)		30 secs. Max
Ramp-down Rate		6 °C/secs. Max
xTime 25°C to Peak Temp (Tp)		8 min. Max
Do not exceed		+260°C

## SOD-323 PACKAGE OUTLINE DRAWING



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

## SUGGESTED LAND PATTERN



SYM	DIMENSIONS	
	MILLIMETERS	
	INCHES	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031